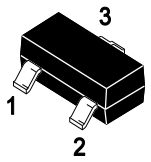
LP2128LT1G

20V P-Channel Enhancement-Mode MOSFET

1. FEATURES

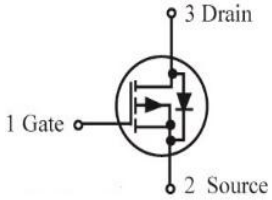
- VDS =-20V
- Advanced trench process technology
- High Density Cell Design For Ultra Low On-Resistance
- Fully Characterized Avalanche Voltage and Current
- We declare that the material of product compliance with RoHS requirements and Halogen Free.



SOT23(TO-236AB)

2. APPLICATIONS

- Simple Drive Requirement
- Small Package Outline
- Surface Mount Device



3. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LP2128LT1G	PA2	3000/Tape&Reel
LP2128LT3G	PA2	10000/Tape&Reel

4. MAXIMUM RATINGS(Ta = 25ºC)

Parameter	Symbol	Limits	Unit
Drain–Source Voltage	VDSS	-20	V
Gate–to–Source Voltage	VGS	±12	V
Drain Current(Note 1) – Continuous TA = 25°C – Pulsed	 ID IDM	 -6 -24	A
Avalanche Current(L=0.1mH)	IAS	12	A
Avalanche Energy(L=0.1mH)	EAS	7.3	mJ

5. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Power Dissipation (Note 2)	PD	1.1	W
Maximum Junction-to-Ambient (Note 2)	RΘJA	110	ºC/W
Junction and Storage temperature	TJ,Tstg	−55~+150	℃

1.Repetitive Rating: Pulse width limited by the maximum junction temperature.

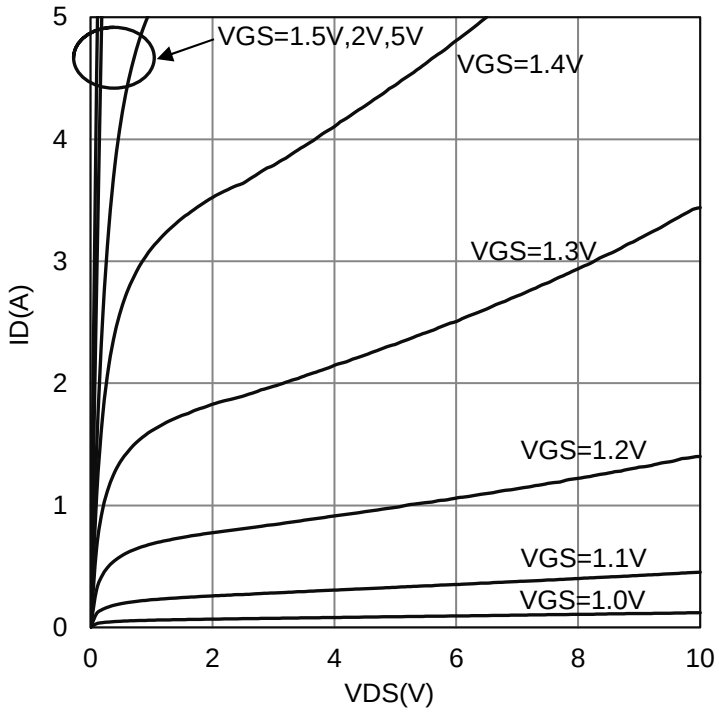
2.Surface mounted on "1.5 x 1.5" FR4 board using 1 sq in pad, 2 oz Cu.

6. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

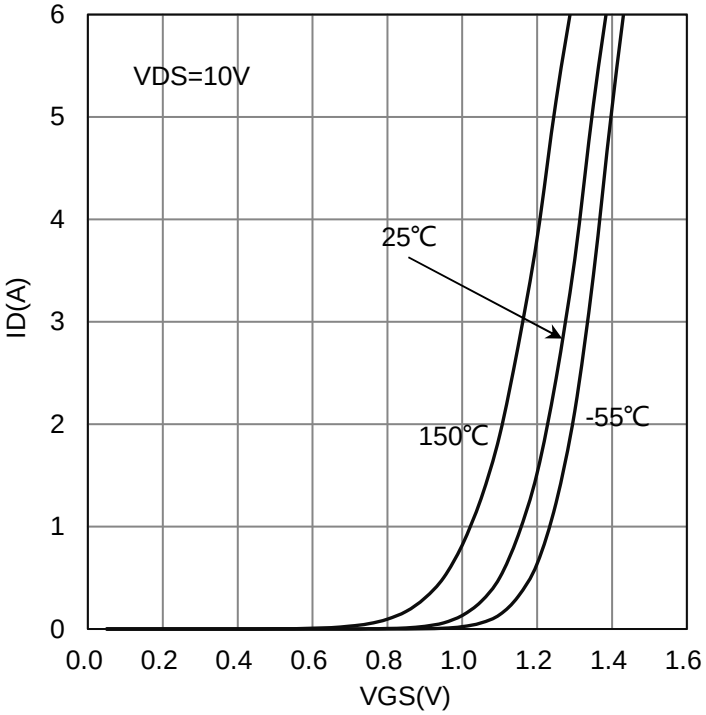
Characteristic		Symbol	Min.	Typ.	Max.	Unit
Static						
Drain–Source Breakdown Voltage (VGS = 0, ID = -250μA)		VBRDSS	-20	-	-	V
Zero Gate Voltage Drain Current (VGS = 0, VDS = -20 V)		IDSS	-	-	-1	μA
Gate–Body Leakage Current (VGS = ±12 V,VDS=0V)		IGSS	-	-	±100	nA
Gate Threshold Voltage (VDS = VGS, ID = -250μA)		VGS(th)	-0.45	-	-0.9	V
Static Drain–Source On–State Resistance (VGS = -4.5 V, ID = -2.4 A) (VGS = -2.5 V, ID = -2 A) (VGS = -1.8 V, ID = -1 A)		RDS(on)	- - -	17 25 47	28 41 78	mΩ
Dynamic(Note 3)						
Input Capacitance (VGS = 0 V, f = 1.0MHz,VDS= -4 V)		Ciss	-	1038	-	pF
Output Capacitance (VGS = 0 V, f = 1.0MHz,VDS= -4 V)		Coss	-	110	-	pF
Reverse Transfer Capacitance (VGS = 0 V, f = 1.0MHz,VDS= -4 V)		Crss	-	92	-	pF
Total Gate Charge	(VDS=-10V,VGS=-4.5V,ID=-2.4A)	Qg	-	11	-	nC
Gate to Source Charg		Qgs	-	1.7	-	
Gate to Drain Charge		Qgd	-	2.5	-	
Turn-On Delay Time	(VDD=-4V,RL=4Ω,RG=6.2Ω,VGEN=-4.5V,ID=-1A)	td(on)	-	6.2	-	ns
Rise Time		tr	-	14.4	-	
Turn-Off Delay Time		td(off)	-	46	-	
Fall Time		tf	-	24	-	
Diode Forward Voltage (IS = -1.6A, VGS = 0V)		VSD	-	-	-1.2	V

3.Pulse Test: Pulse Width ≤300 μs, Duty Cycle ≤2.0%.

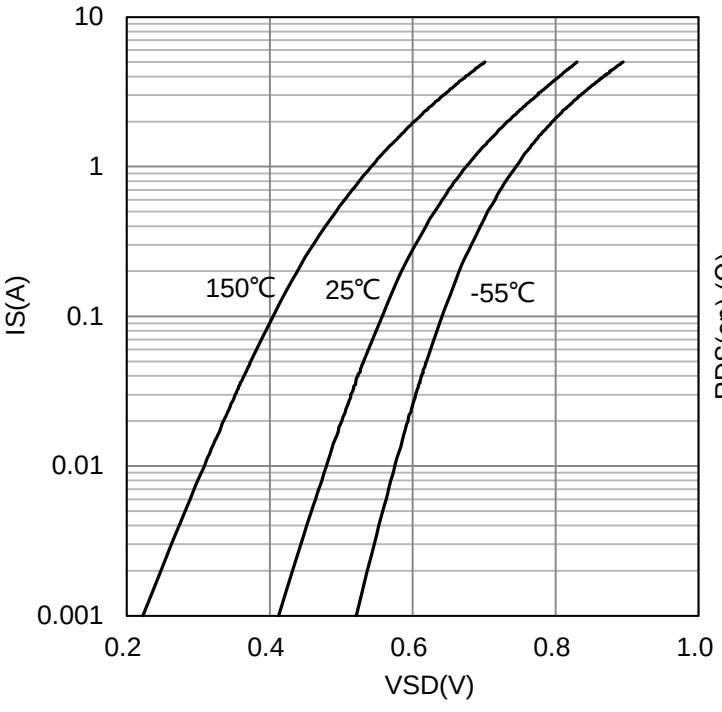
7.ELECTRICAL CHARACTERISTICS CURVES



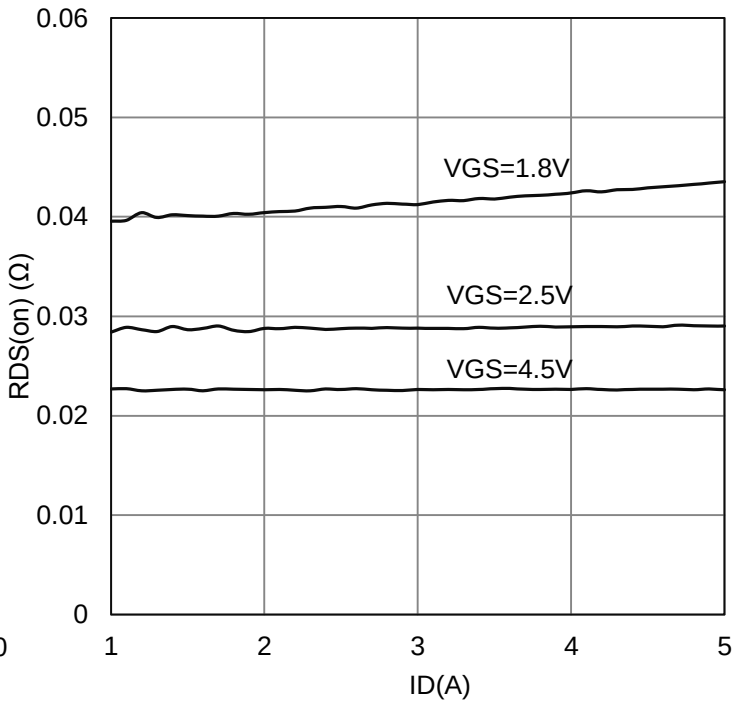
ID vs. VDS



ID vs. VGS

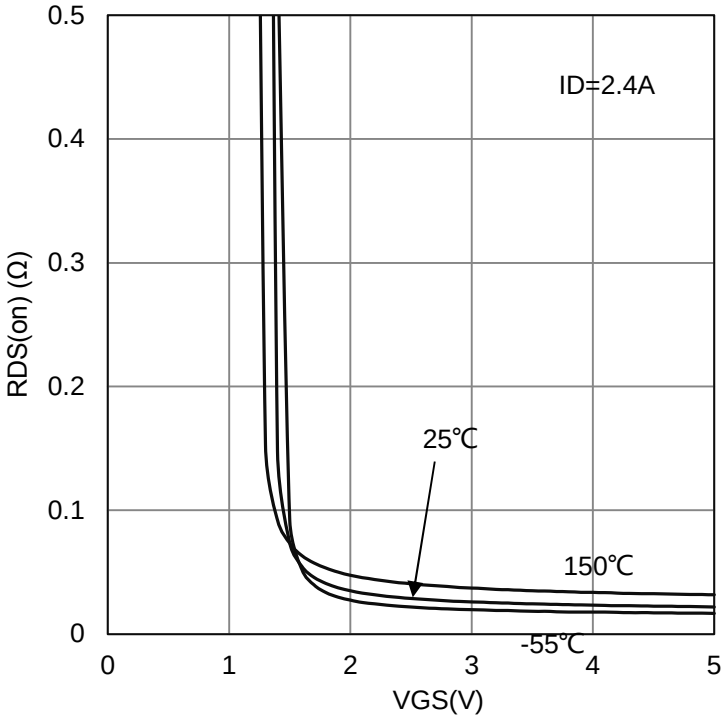


IS vs. VSD

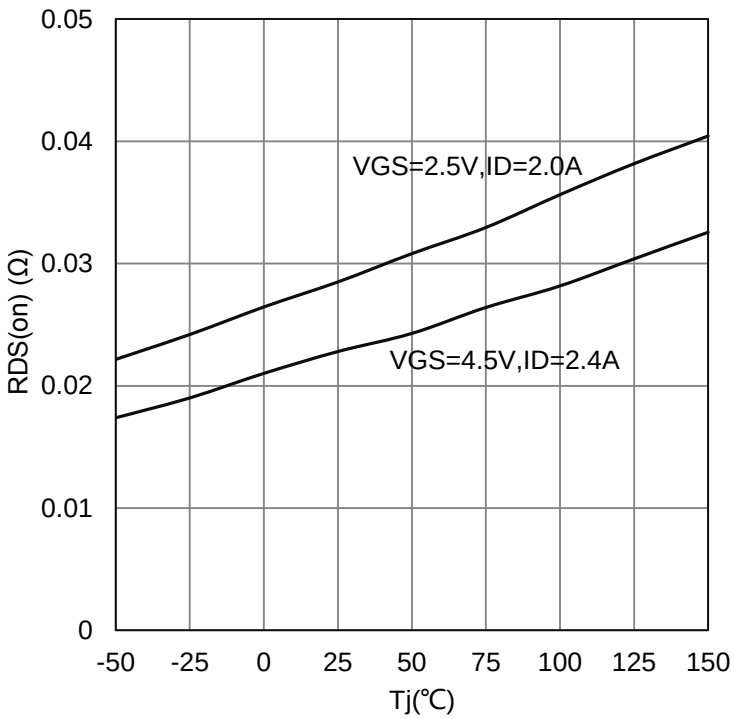


RDS(on) vs. ID

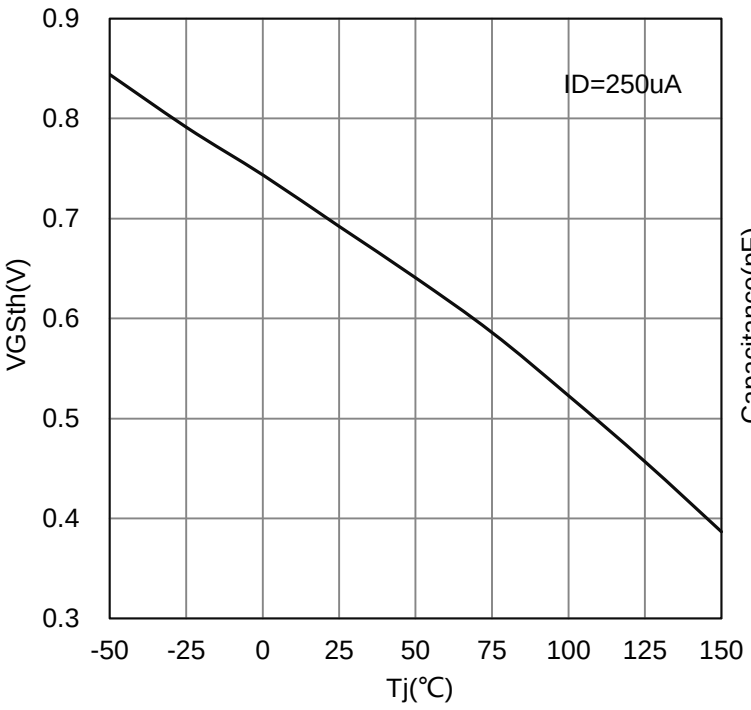
7.ELECTRICAL CHARACTERISTICS CURVES(Con.)



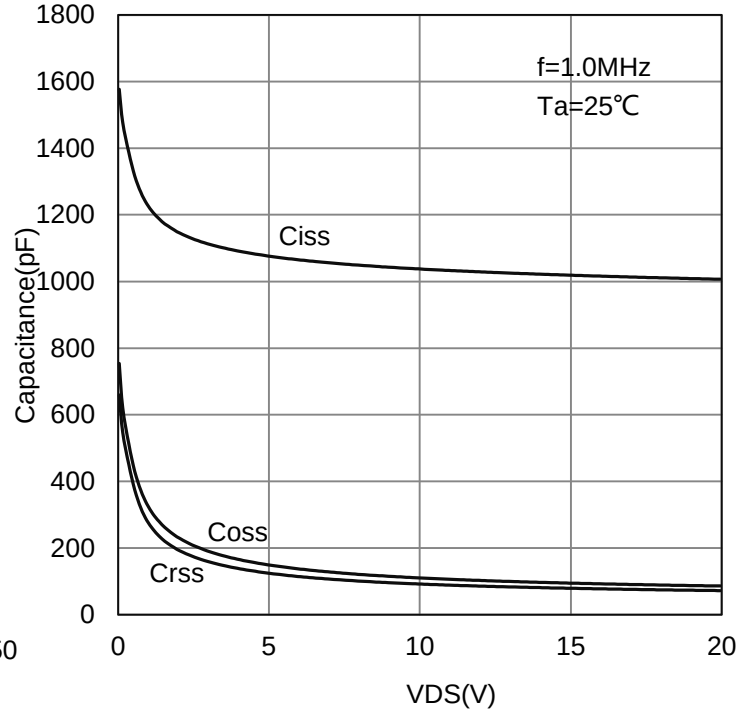
RDS(on) vs. VGS



RDS(on) vs. Tj

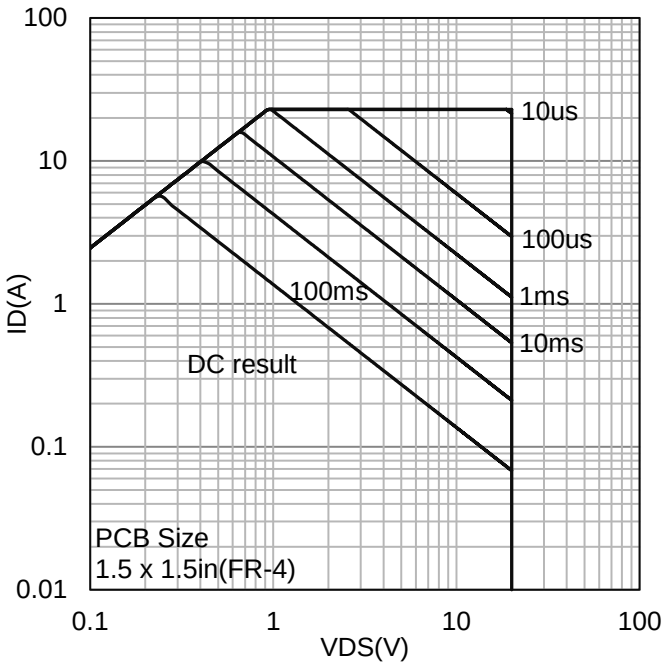


VGSth vs. Tj

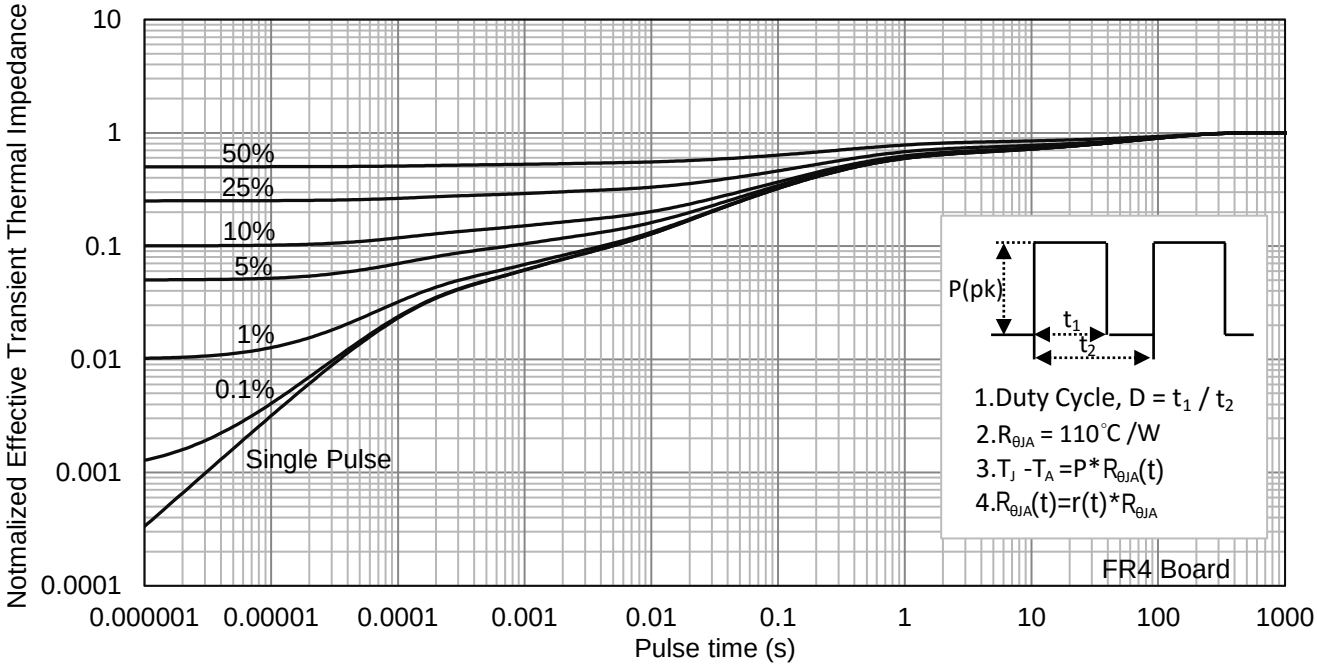


Capacitance

7.ELECTRICAL CHARACTERISTICS CURVES(Con.)

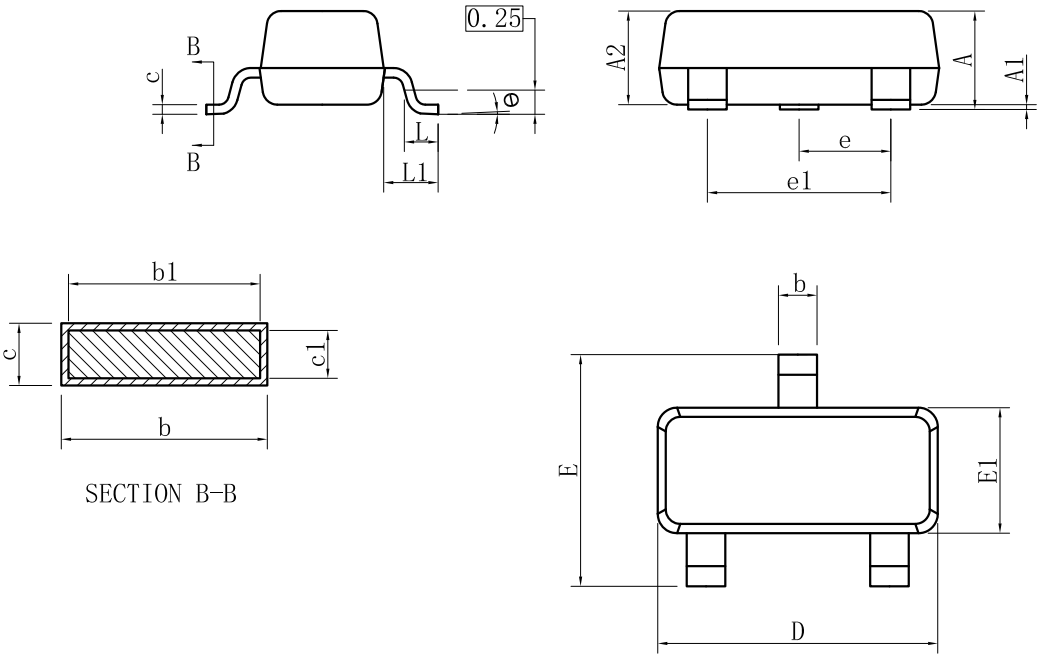


Safe Operating Area



Thermal Response

8.OUTLINE AND DIMENSIONS

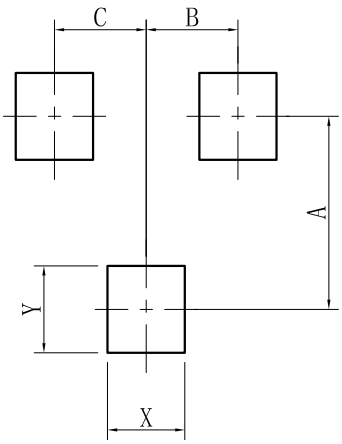


SOT23			
DIM	MIN	NOR	MAX
A	0.89	-	1.12
A1	0.01	-	0.10
A2	0.88	0.95	1.02
b	0.30	-	0.50
b1	0.30	0.40	0.45
c	0.08	-	0.20
c1	0.08	0.10	0.16
D	2.80	2.90	3.04
E	2.10	-	2.64
E1	1.20	1.30	1.40
e	0.95BSC		
e1	1.90BSC		
L	0.40	0.46	0.60
L1	0.54REF		
θ	0°	-	8°
All Dimensions in mm			

GENERAL NOTES

1. Top package surface finish Ra0.4±0.2um
2. Bottom package surface finish Ra0.7±0.2um
3. Side package surface finish Ra0.4±0.2um

9.SOLDERING FOOTPRINT



SOT23	
DIM	(mm)
X	0.80
Y	0.90
A	2.00
B	0.95
C	0.95

DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.

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